### INTEGRATED CIRCUITS

# DATA SHEET

### **CBT3857**

10-bit bus switch with 10 k $\Omega$  pull-down termination resistors

Product specification Supersedes data of 1998 Dec 10





### 10-bit bus switch with 10 k $\Omega$ pull-down termination resistors

**CBT3857** 

### **FEATURES**

- Enable signal is SSTL\_2 compatible
- Optimized for use in Double Data Rate (DDR) SDRAM applications
- Flow-through architecture optimizes PCB layout
- Designed to be used with 200 Mbps
- Switch on resistance is designed to eliminate the need for series resistor to DDR SDRAM
- Internal 10 kΩ pull-down resistors on B port
- Internal 50  $k\Omega$  pull-up resistor on output enable input
- Full DDR solution provided when used with SSTL16857 and PCK857
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114,
   200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101

### **DESCRIPTION**

This 10-bit bus switch is designed for 3 V to 3.6 V  $V_{CC}$  operation and SSTL\_2 output enable ( $\overline{OE}$ ) input levels.

When  $\overline{OE}$  is LOW, the 10-bit bus switch is on and port A is connected to port B. When  $\overline{OE}$  is HIGH, the switch is open, and a high-impedance state exists between the two ports.

The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The CBT3857 is characterized for operation from 0°C to +85°C.

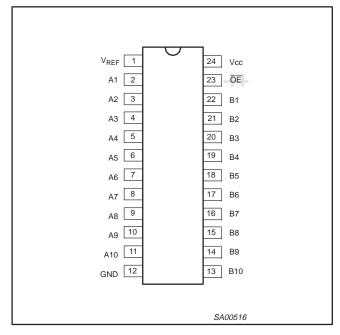
### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0 V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Yn	$C_L = 30 \text{ pF}; V_{CC} = 3.3 \text{ V}$	720	ps
C <sub>IN</sub>	Input capacitance	$V_I = 0 \text{ V or } V_{CC}$	2.8	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; $V_O = 0 \text{ V or } V_{CC}$	6.4	pF
I <sub>CCZ</sub>	Total supply current	V <sub>CC</sub> = 3.6 V	1	mA

### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
24-Pin Plastic TSSOP Type I	0°C to +85°C	CBT3857 PW	SOT355-1

### **PIN CONFIGURATION**



### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	$V_{REF}$	Reference output voltage
2, 3, 4, 5, 6, 7, 8, 9, 10, 11	A1–A10	Inputs
12	GND	Ground (V)
22, 21, 20, 19, 18, 17, 16, 15, 14, 13	B1-B10	Outputs
23	ŌĒ	Output enable
24	V <sub>CC</sub>	Positive supply voltage

### **FUNCTION TABLE**

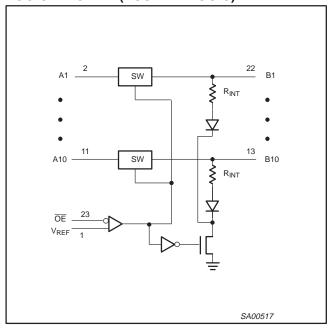
INPUT OE	FUNCTION
L	A port = B port
Н	Disconnect

H = High voltage levelL = Low voltage level

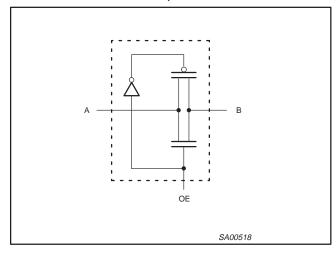
### 10-bit bus switch with 10 k $\Omega$ pull-down termination resistors

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### **LOGIC DIAGRAM (POSITIVE LOGIC)**



### SIMPLIFIED SCHEMATIC, EACH FET SWITCH



### ABSOLUTE MAXIMUM RATINGS1, 3

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input clamp current	V <sub>I/O</sub> < 0	-50	mA
VI	DC input voltage range (OE only) <sup>2</sup>		V <sub>CC</sub> + 0.5	V
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C
VI	DC input voltage range (except OE) <sup>2</sup>		-0.5 to 4.6	V

### NOTES:

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

  2. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	DADAMETED		LINIT		
STWIBUL	PARAMETER	Min	Тур	Max	UNIT
V <sub>CC</sub>	DC supply voltage	3	3.3	3.6	V
$V_{REF}$	Reference voltage (0.38 x V <sub>CC</sub> )	1.15	1.25	1.35	V
V <sub>IH</sub>	AC high-level input voltage	V <sub>REF</sub> + 350 mV			V
$V_{IL}$	AC low-level Input voltage			V <sub>REF</sub> – 350 mV	V
$V_{IH}$	DC high-level input voltage	V <sub>REF</sub> + 180 mV			V
V <sub>IL</sub>	DC low-level Input voltage			V <sub>REF</sub> – 180 mV	V
T <sub>amb</sub>	Operating free-air temperature range	0		+85	°C

### NOTE:

1. All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.

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### DC ELECTRICAL CHARACTERISTICS

SYMBOL PARAMETER			TEST CONDITIONS				UNIT
		TEST CONDITIONS					
				Min	Typ <sup>1</sup>	Max	1
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 3 \text{ V; } I_{I} = -18 \text{ mA}$				-1.2	V
			ŌĒ		±0.73	±500	μΑ
	Innut lookaga aurrant	V 26 V: V V 07 CND	A Port		±0.1	±1	μΑ
I <sub>I</sub>	I <sub>I</sub> Input leakage current	$V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND}$	B Port		±20	±500	μΑ
			V <sub>REF</sub>		±0.1	±1	μΑ
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6 \text{ V}; I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$	)		0.7	1.5	mA
CI	Control pins	V <sub>I</sub> = 3 V or 0			2.8		pF
Ci <sub>O(OFF)</sub>	Power-off leakage current	$V_O = 3 \text{ V or 0}; \overline{OE} = V_{CC}$			6.4		pF
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}; V_A = 0.8 \text{ V}; V_B = 0.00 \text{ V}$	I.15 V	20	24	30	
$r_{on}^2$	On-resistance	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}; V_A = 1.7 \text{ V}; V_B = 1.0 \text{ V}$	1.35 V	20	24	30	Ω
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V; } V_{I} = 1.25 \text{ V; } I_{I} = \pm$	10 mA	20	24	30	]
r <sub>off</sub> <sup>2</sup>	Off-resistance	V <sub>CC</sub> = 3 V to 3.6 V; V <sub>I</sub> = 1.65 V		1			МΩ

#### NOTES:

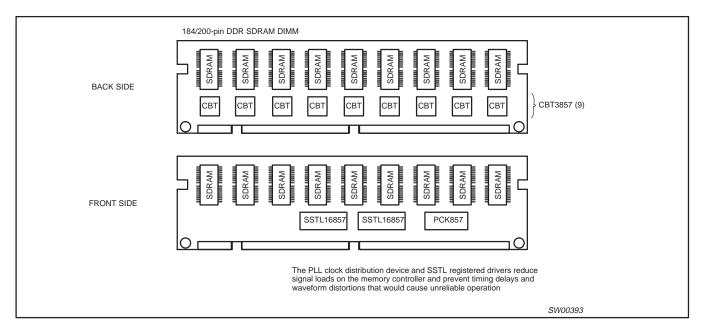
- 1. All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_{amb} = 25^{\circ}\text{C}$
- 2. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On–state resistance is determined by the lowest voltage of the two (A or B) terminals.

### **AC CHARACTERISTICS**

SYMBOL PARAMETER		FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = +3.3	UNIT	
STIMBOL	PARAMETER	PROM (INPOT)	10 (001701)	Min	Max	ONII
t <sub>pd</sub>	Propagation delay <sup>1</sup>	A or B	B or A		750	ps
t <sub>en</sub>	enable	ŌĒ	A or B	1	3	ns
t <sub>dis</sub>	disable	ŌĒ	A or B	1	3	ns

### NOTE:

 The propagation delay is based on the RC time constant of the typical on–state resistance of the switch and a load capacitance, when driven by an ideal voltage source (zero output impedance); 24 Ω × 30 pF.



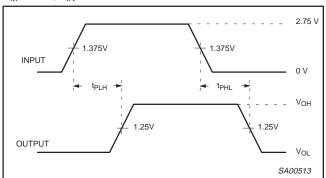
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### 10-bit bus switch with 10 $k\Omega$ pull-down termination resistors

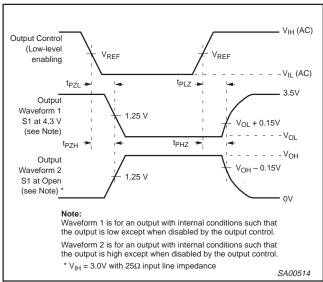
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### **AC WAVEFORMS**

 $V_M = 1.5 \text{ V}, V_{IN} = \text{GND to } 3.0 \text{ V}$ 

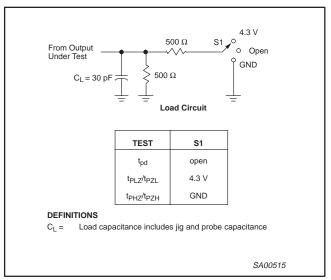


Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

### **TEST CIRCUIT AND WAVEFORMS**



#### NOTES:

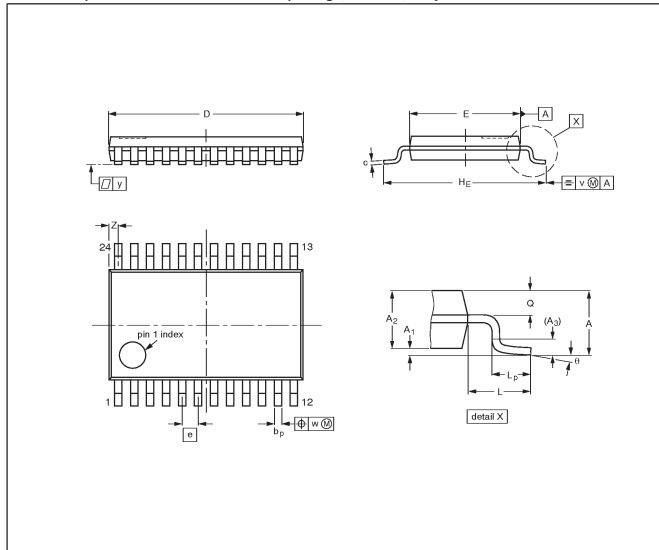
- 1. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- The outputs are measured one at a time with one transition per measurement.

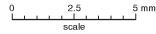
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TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1





### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT355-1		MO-153AD			<del>93-06-16</del> 95-02-04

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**NOTES** 

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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